SGM2051
1.2A, Ultra-High PSRR, Fast Load Transient, Bias Rail CMOS Voltage Regulator

GENERAL DESCRIPTION

The SGM2051 is an ultra-high PSRR, fast transient response, low noise and low dropout voltage linear regulator which is designed using CMOS technology. It provides 1.2A output current capability. The operating input voltage range is from 0.5V to 5.5V and bias supply voltage range is from 2.5V to 5.5V. The adjustable output voltage range is from 0.5V to 3.3V.

Other features include logic-controlled shutdown mode, short-circuit current limit and thermal shutdown protection. The SGM2051 has automatic discharge function to quickly discharge V_{OUT} in the disabled status.

The SGM2051 is available in a Green WLCSP-0.8×1.2-6B-A package. It operates over an operating temperature range of -40℃ to +125℃.

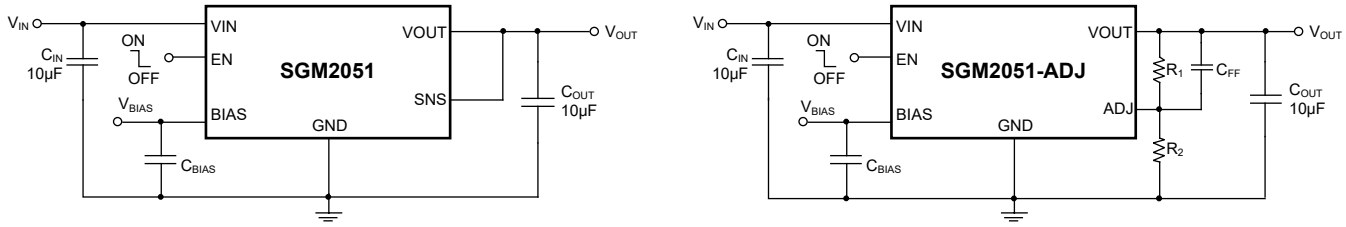
FEATURES

- **Input Supply Voltage Range: 0.5V to 5.5V**
- **Bias Supply Voltage Range: 2.5V to 5.5V**
- **Adjustable Output Voltage Range: 0.5V to 3.3V**
- **Output Voltage Accuracy: ±0.8% at +25℃**
- **High PSRR: 70dB (TYP) at 1kHz**
- **Low Dropout Voltage: 60mV (TYP) at 1.2A**
- **Low Bias Input Current: 96μA (TYP)**
- **Very Low Bias Input Current in Shutdown: < 1μA**
- **Low Noise: 29μV_{RMS} (TYP)**
- **Fast Load Transient Response**
- **Output Current Limit**
- **Stable with Small Case Size Ceramic Capacitors**
- **Thermal Shutdown Protection**
- **Logic Level Enable Input for ON/OFF Control**
- **-40℃ to +125℃ Operating Temperature Range**
- **Available in a Green WLCSP-0.8×1.2-6B-A Package**

APPLICATIONS

Portable Equipment
Smartphone
Industrial and medical Equipment

TYPICAL APPLICATION



Fixed Voltage Typical Application Circuit **Adjustable Voltage Typical Application Circuit**

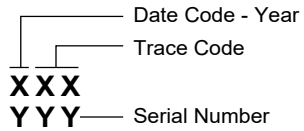
Figure 1. Typical Application Circuits

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM2051-0.75	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-0.75XG	XXX CZ5	Tape and Reel, 3000
SGM2051-0.8	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-0.8XG	XXX CZ6	Tape and Reel, 3000
SGM2051-0.85	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-0.85XG	XXX CZ7	Tape and Reel, 3000
SGM2051-1.0	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-1.0XG	XXX CZ8	Tape and Reel, 3000
SGM2051-1.05	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-1.05XG	XXX CZ9	Tape and Reel, 3000
SGM2051-1.1	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-1.1XG	XXX CZB	Tape and Reel, 3000
SGM2051-1.15	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-1.15XG	XXX ORD	Tape and Reel, 3000
SGM2051-1.2	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-1.2XG	XXX CZC	Tape and Reel, 3000
SGM2051-1.8	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-1.8XG	XXX CZD	Tape and Reel, 3000
SGM2051-2.8	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-2.8XG	XXX CZE	Tape and Reel, 3000
SGM2051-3.0	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-3.0XG	XXX CZF	Tape and Reel, 3000
SGM2051-3.3	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-3.3XG	XXX R00	Tape and Reel, 3000
SGM2051-ADJ	WLCSP-0.8×1.2-6B-A	-40℃ to +125℃	SGM2051-ADJXG	XXX R01	Tape and Reel, 3000

MARKING INFORMATION

NOTE: X = Date Code. XX = Trace Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

IN, BIAS, EN to GND ..... -0.3V to 6V
OUT, SNS, ADJ to GND ..... -0.3V to Min(V_{IN} + 0.3V, 6V)
Package Thermal Resistance
WLCSP-0.8×1.2-6B-A, θ_{JA} ..... 177℃/W
WLCSP-0.8×1.2-6B-A, θ_{JB} ..... 32℃/W
WLCSP-0.8×1.2-6B-A, θ_{JC} ..... 48℃/W
Junction Temperature ..... +150℃
Storage Temperature Range ..... -65℃ to +150℃
Lead Temperature (Soldering, 10s) ..... +260℃
ESD Susceptibility
HBM 5000V
CDM 1000V

RECOMMENDED OPERATING CONDITIONS

Input Supply Voltage Range, V_{IN} ..... 0.5V to 5.5V
Bias Supply Voltage Range, V_{BIAS} ..... 2.5V to 5.5V
Bias Effective Capacitance, C_{BIAS} ..... 1μF (MIN)
Input Effective Capacitance, C_{IN} ..... 2.2μF (MIN)
Output Effective Capacitance, C_{OUT} ..... 4.7μF to 22μF
Operating Junction Temperature Range ..... -40℃ to +125℃

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

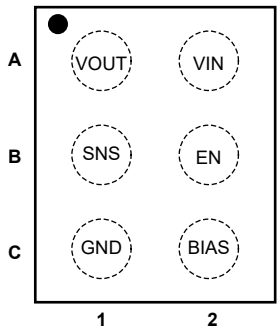
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

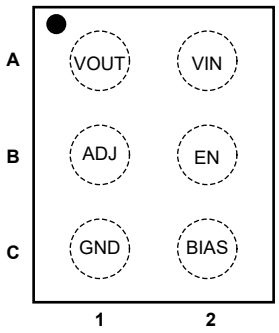
PIN CONFIGURATIONS

SGM2051-Fixed Output
(TOP VIEW)



WLCSP-0.8×1.2-6B-A

SGM2051-ADJ
(TOP VIEW)



WLCSP-0.8×1.2-6B-A

PIN DESCRIPTION

PIN	NAME	FUNCTION
A1	VOUT	Regulator Output Pin. It is recommended to use an output capacitor with effective capacitance in the range of 4.7μF to 22μF.
A2	VIN	Input Voltage Supply Pin.
B1	SNS	Output Voltage Sense Input Pin (fixed voltage version only). Connect this pin to the load side of the output trace only in the fixed voltage version.
	ADJ	Feedback Input Pin (adjustable voltage version only). Connect this pin to the external resistor divider to adjust the output voltage. Place the resistors as close as possible to this pin.
B2	EN	Enable Pin. Drive EN high to turn on the regulator. Drive EN low to turn off the regulator. The EN pin has an internal 0.26μA pull-down current source which ensures that the device is turned off when the EN pin is floated.
C1	GND	Ground.
C2	BIAS	Bias Supply Voltage Pin for Internal Control Circuits. This pin is monitored by internal under-voltage lockout circuit.

ELECTRICAL CHARACTERISTICS

(V_{IN} = $V_{OUT(NOM)}$ + 0.3V, V_{BIAS} = 2.5V or ($V_{OUT(NOM)}$ + 1.6V) (whichever is greater), V_{EN} = 1V, I_{OUT} = 1mA, C_{IN} = C_{OUT} = 10μF and C_{BIAS} = 2.2μF, T_J = -40℃ to +125℃, typical values are at T_J = +25℃, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Supply Voltage Range	V_{IN}			$V_{OUT(NOM)}$ + V_{DROP_VIN}		5.5	V
Bias Supply Voltage Range	V_{BIAS}			($V_{OUT(NOM)}$ + 1.6) ≥ 2.5		5.5	V
Under-Voltage Lockout	V_{UVLO}	V_{BIAS} rising			1.65	2	V
		Hysteresis			0.3		V
Feedback Voltage	V_{FB}	SGM2051-ADJ, T_J = +25℃		0.496	0.5	0.504	V
		SGM2051-ADJ		0.492		0.508	
Output Voltage Accuracy	V_{OUT}	V_{IN} = ($V_{OUT(NOM)}$ + 0.3V) to 5.5V, V_{BIAS} = 2.5V or ($V_{OUT(NOM)}$ + 1.6V) to 5.5V, I_{OUT} = 1mA to 1.2A	T_J = +25℃	-0.8		0.8	%
			T_J = -40℃ to +125℃	-1.6		1.6	
V_{IN} Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \times V_{OUT}}$	V_{IN} = ($V_{OUT(NOM)}$ + 0.3V) to 5.5V, 0.5V ≤ $V_{OUT(NOM)}$ ≤ 1.8V			0.001	0.03	%/V
		V_{IN} = ($V_{OUT(NOM)}$ + 0.3V) to 5.5V, 1.8V < $V_{OUT(NOM)}$ ≤ 3.3V			0.004	0.05	
V_{BIAS} Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{BIAS} \times V_{OUT}}$	V_{BIAS} = 2.5V or ($V_{OUT(NOM)}$ + 1.6V) to 5.5V, 0.5V ≤ $V_{OUT(NOM)}$ ≤ 1.8V			0.02	0.1	%/V
		V_{BIAS} = ($V_{OUT(NOM)}$ + 1.6V) to 5.5V, 1.8V < $V_{OUT(NOM)}$ ≤ 3.3V			0.07	0.28	
Load Regulation	ΔV_{OUT}	I_{OUT} = 1mA to 1.2A			1	6	mV
V_{IN} Dropout Voltage (1)	V_{DROP_VIN}	I_{OUT} = 1.2A			60	104	mV
V_{BIAS} Dropout Voltage (2) (3)	V_{DROP_BIAS}	I_{OUT} = 1.2A, V_{IN} = V_{BIAS}			1.1	1.4	V
Output Current Limit	I_{LIMIT}	V_{OUT} = 90% × $V_{OUT(NOM)}$		1.35	2.2		A
Short Current Limit	I_{SHORT}	V_{OUT} = 0V			1.1		A
ADJ Pin Operating Current	I_{ADJ}			-10		10	nA
BIAS Pin Quiescent Current	I_{BIAS}	V_{BIAS} = 5.5V			96	135	μA
VIN Pin Quiescent Current	I_{IN}	V_{IN} = 5.5V, I_{OUT} = 0mA			35	100	μA
BIAS Pin Shutdown Current	$I_{BIAS(DIS)}$	V_{EN} = 0V				1	μA
VIN Pin Shutdown Current	$I_{VIN(DIS)}$	V_{EN} = 0V, T_J = +25℃				0.5	μA
		V_{EN} = 0V				8	
EN Input Voltage	V_{IH}	Logic high		1			V
	V_{IL}	Logic low, T_J = +25℃				0.4	V
EN Pull-Down Current	I_{EN}	V_{EN} = 5.5V, V_{BIAS} = 5.5V			0.26	1	μA
Turn-On Time	t_{ON}	$V_{OUT(NOM)}$ = 1.1V, from assertion of V_{EN} to V_{OUT} = 98% × $V_{OUT(NOM)}$			150		μs
V_{IN} Power Supply Rejection Ratio	PSRR	V_{IN} to V_{OUT}, f = 1kHz, $V_{OUT(NOM)}$ = 1.1V, I_{OUT} = 150mA, V_{IN} ≥ 1.6V			70		dB
V_{BIAS} Power Supply Rejection Ratio		V_{BIAS} to V_{OUT}, f = 1kHz, $V_{OUT(NOM)}$ = 1.1V, I_{OUT} = 150mA, V_{IN} ≥ 1.6V			80		dB
Output Voltage Noise	e_n	$V_{OUT(NOM)}$ = 1.1V, V_{IN} = 1.6V, f = 10Hz to 100kHz			29		μV_{RMS}
Output Discharge Resistance	R_{DIS}	V_{EN} = 0V, V_{OUT} = 0.5V		50	80	120	Ω
Thermal Shutdown Temperature	T_{SHDN}				160		℃
Thermal Shutdown Hysteresis	ΔT_{SHDN}				20		℃

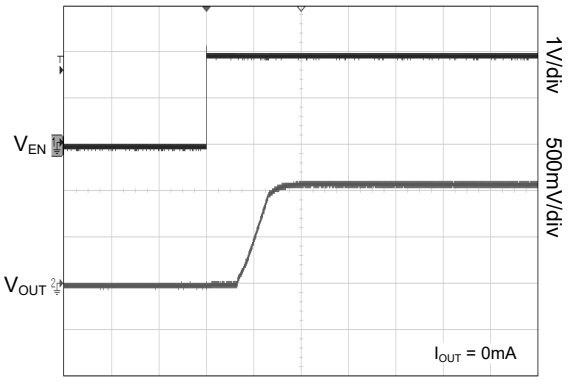
NOTES:

1. V_{IN} dropout voltage is defined as the difference between V_{IN} and V_{OUT} when V_{OUT} falls to 95% × $V_{OUT(NOM)}$.
2. V_{BIAS} dropout voltage refers to V_{BIAS} - V_{OUT} when the VIN and BIAS pins are connected together and V_{OUT} falls to 95% × $V_{OUT(NOM)}$.
3. For output voltages lower than 1.6V, V_{BIAS} dropout voltage is not applicable because the minimum bias supply voltage is 2.5V.

TYPICAL PERFORMANCE CHARACTERISTICS

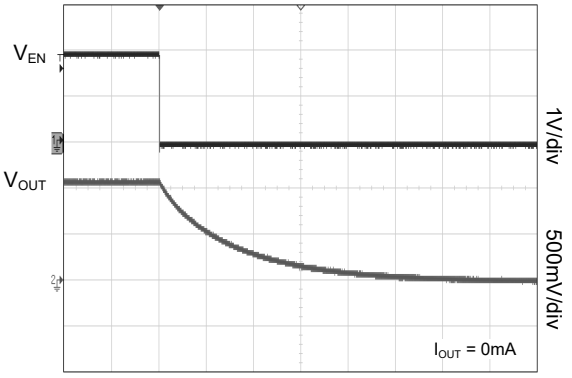
T_J = +25℃, V_{IN} = 1.4V, V_{EN} = V_{BIAS} = 2.7V, $V_{OUT(NOM)}$ = 1.1V, C_{IN} = C_{OUT} = 10μF, C_{BIAS} = 2.2μF, unless otherwise noted.

Turn-On Speed with EN Pin



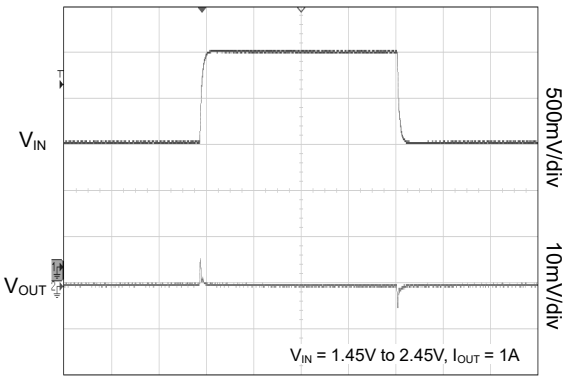
Time (100μs/div)

Turn-Off Speed with EN Pin



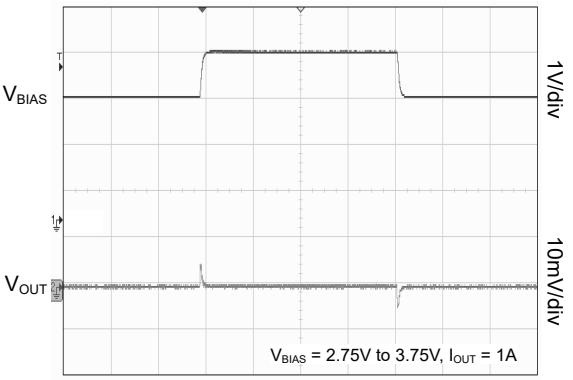
Time (500μs/div)

V_{IN} Line Transient Response



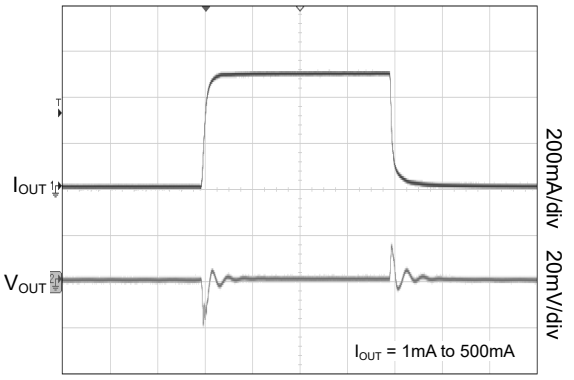
Time (200μs/div)

V_{BIAS} Line Transient Response



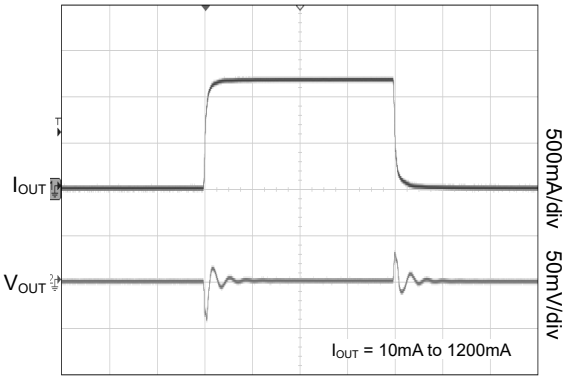
Time (200μs/div)

Load Transient Response



Time (50μs/div)

Load Transient Response

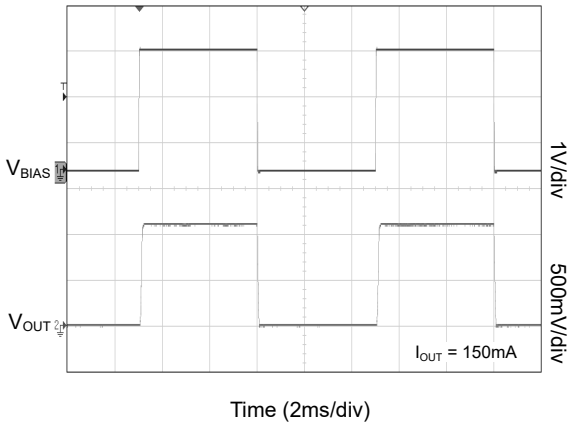


Time (50μs/div)

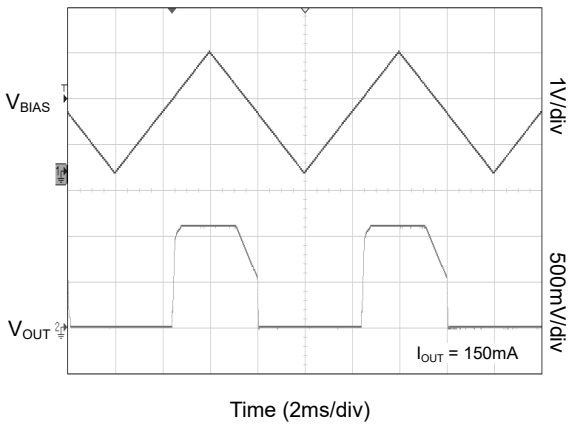
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

T_J = +25℃, V_{IN} = 1.4V, V_{EN} = V_{BIAS} = 2.7V, $V_{OUT(NOM)}$ = 1.1V, C_{IN} = C_{OUT} = 10μF, C_{BIAS} = 2.2μF, unless otherwise noted.

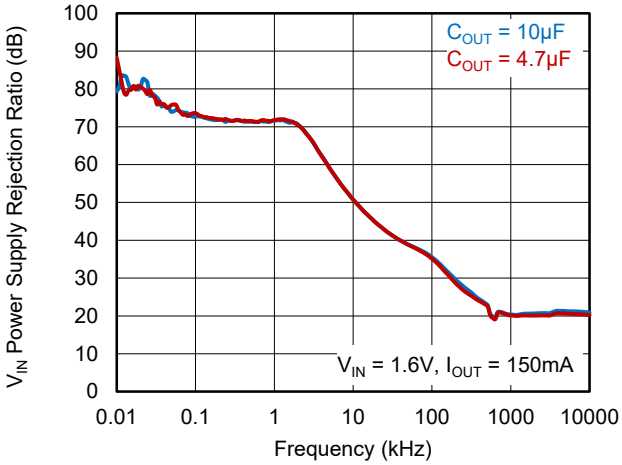
V_{BIAS} Power-Up/Power-Down Output Waveform



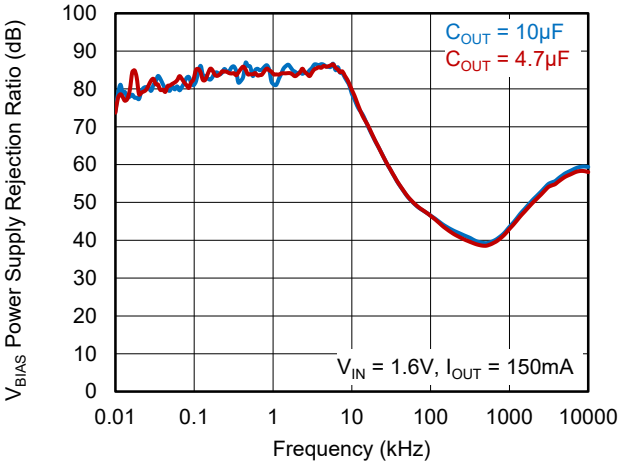
V_{BIAS} Power Ramp-Up/Ramp-Down Output Waveform



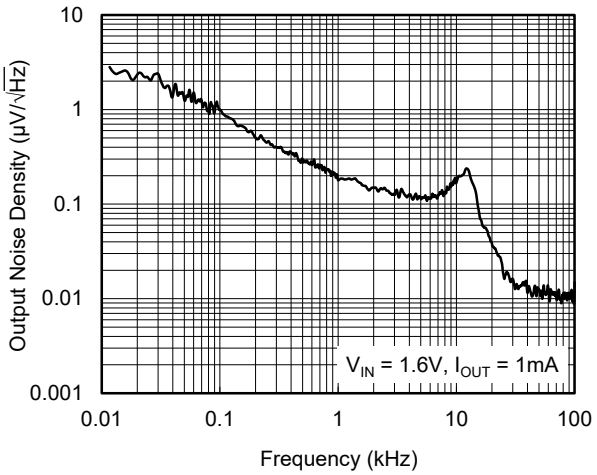
V_{IN} Power Supply Rejection Ratio vs. Frequency



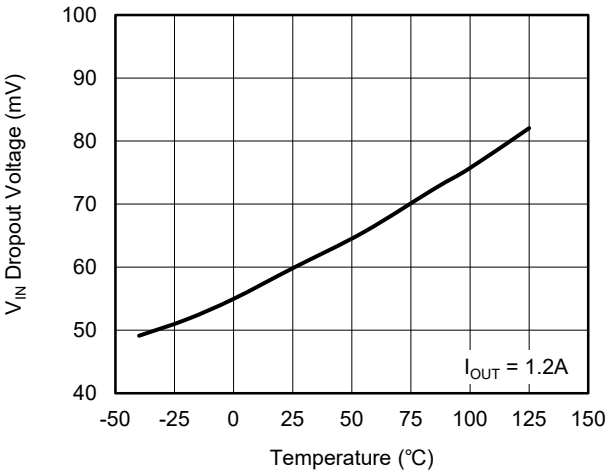
V_{BIAS} Power Supply Rejection Ratio vs. Frequency



Output Noise Density vs. Frequency



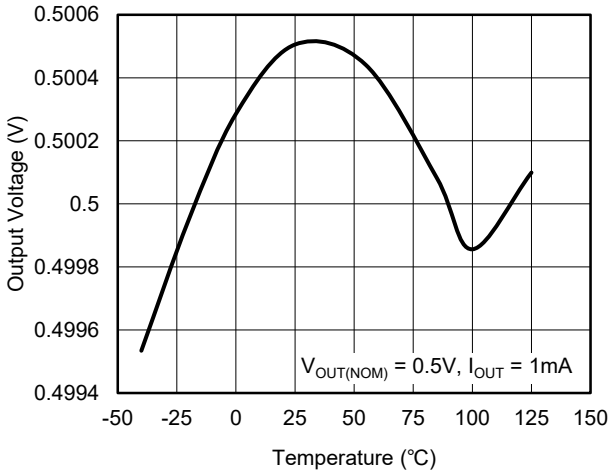
V_{IN} Dropout Voltage vs. Temperature



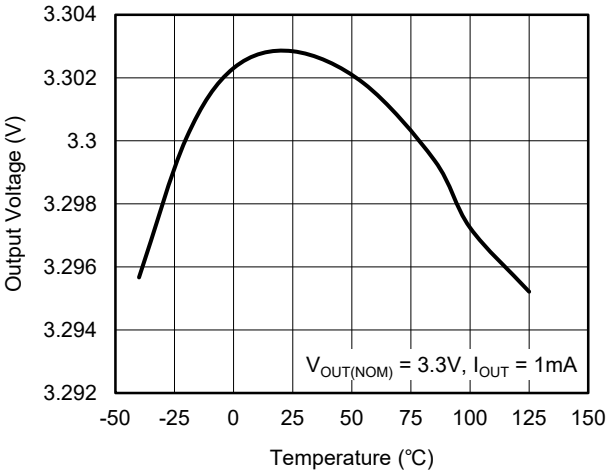
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

T_J = +25℃, V_{IN} = 1.4V, V_{EN} = V_{BIAS} = 2.7V, $V_{OUT(NOM)}$ = 1.1V, C_{IN} = C_{OUT} = 10μF, C_{BIAS} = 2.2μF, unless otherwise noted.

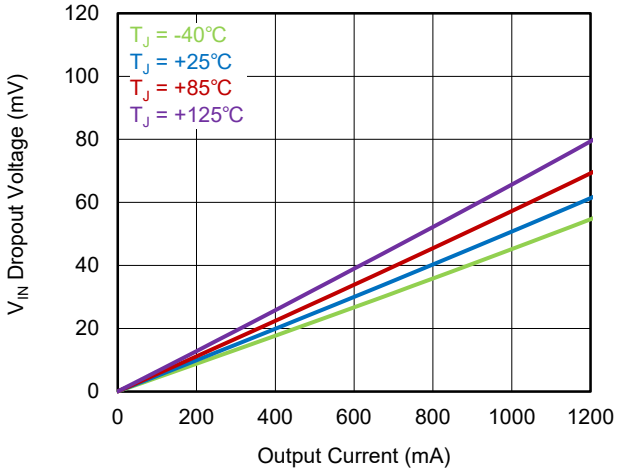
Output Voltage vs. Temperature



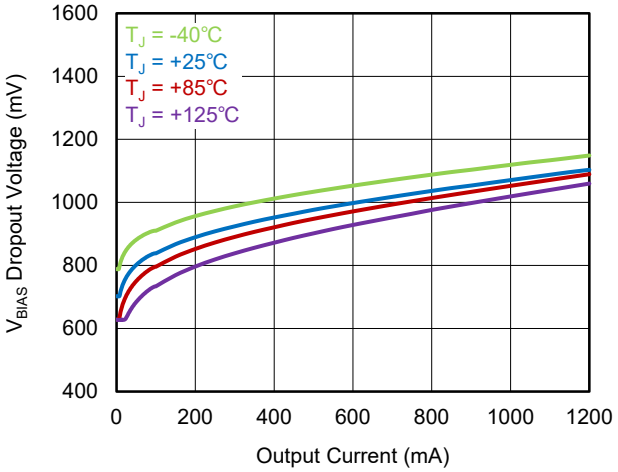
Output Voltage vs. Temperature



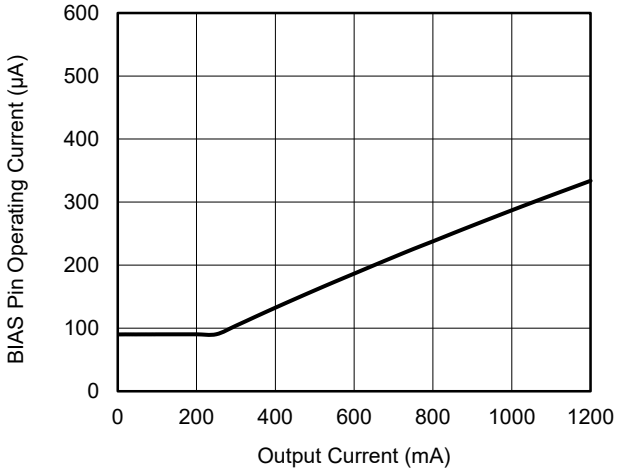
V_{IN} Dropout Voltage vs. Output Current



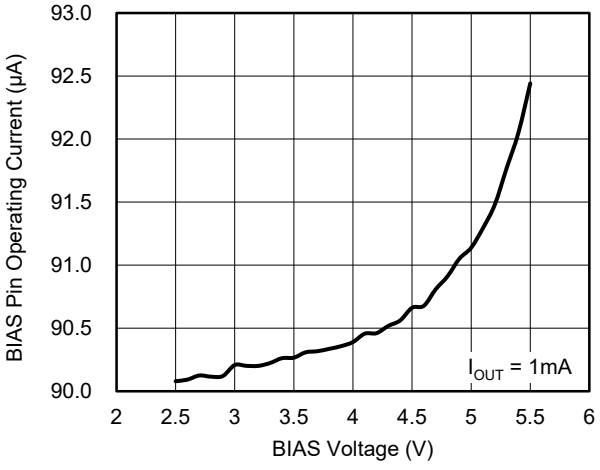
V_{BIAS} Dropout Voltage vs. Output Current



BIAS Pin Operating Current vs. Output Current



BIAS Pin Operating Current vs. BIAS Voltage



FUNCTIONAL BLOCK DIAGRAMS

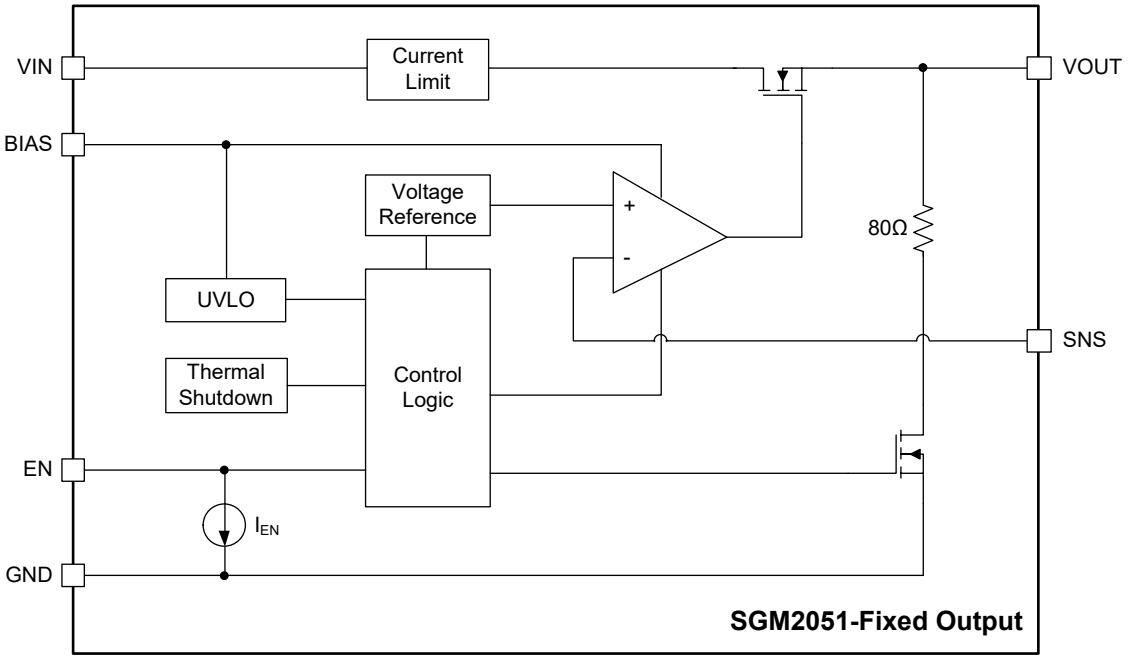


Figure 2. Fixed Output Voltage Internal Block Diagram

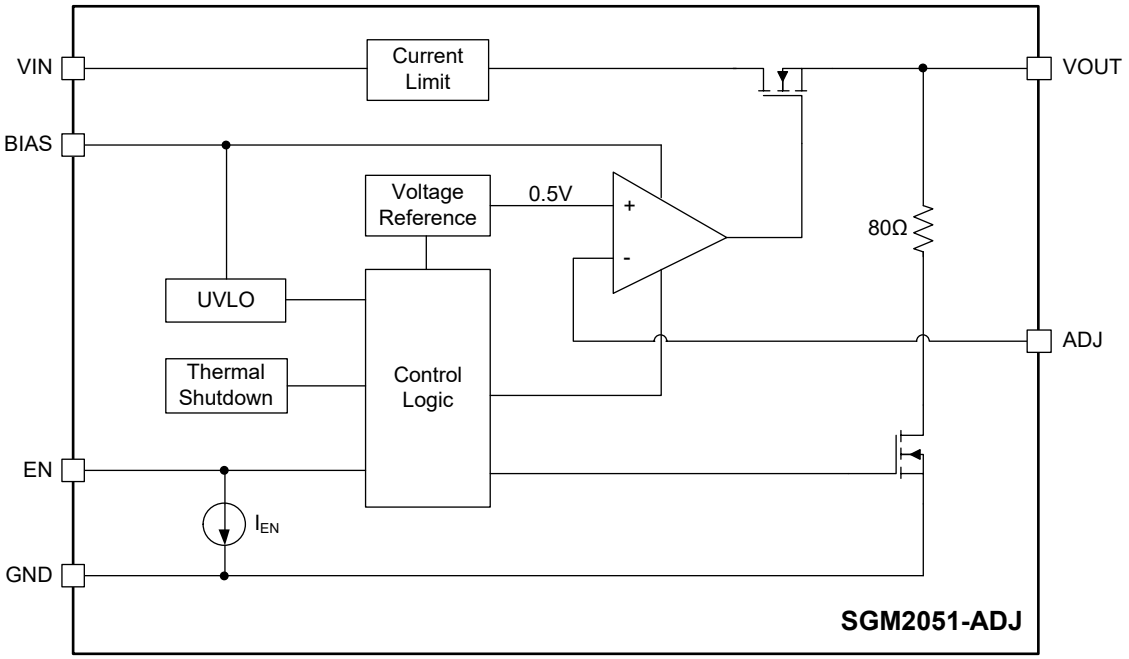


Figure 3. Adjustable Output Voltage Internal Block Diagram

APPLICATION INFORMATION

The SGM2051 is a low noise, fast transient response high performance LDO, it consumes only 96μA (TYP) quiescent current and provides 1.2A output current. The SGM2051 provides the protection function for output overload, output short-circuit condition and overheating.

The SGM2051 is suitable for application which has noise sensitive circuit such as battery-powered equipment and smartphones.

Input Capacitor Selection (C_{IN})

The input decoupling capacitor is necessary to be connected as close as possible to the VIN pin for ensuring the device stability. 2.2μF or greater X7R or X5R ceramic capacitor is selected to get good dynamic performance.

When V_{IN} is required to provide large current instantaneously, a large effective input capacitor is required. Multiple input capacitors can limit the input tracking inductance. Adding more input capacitors is available to restrict the ringing and to keep it below the device absolute maximum ratings.

Output Capacitor Selection (C_{OUT})

The output decoupling capacitor should be located as close as possible to the VOUT pin. A 4.7μF or greater X7R or X5R ceramic capacitor is selected to get good dynamic performance. The minimum effective capacitance of C_{OUT} that SGM2051 can remain stable is 4.7μF. For ceramic capacitor, temperature, DC bias and package size will change the effective capacitance, so enough margin of C_{OUT} must be considered in design. Larger capacitance and lower ESR C_{OUT} will help improve the load transient response and increase the high frequency PSRR.

Enable Operation

The SGM2051 uses the EN pin to enable/disable the device and to deactivate/activate the output automatic discharge function.

When the EN pin voltage is lower than 0.4V, the device is in shutdown state, there is no current flowing from VIN to VOUT pins. In this state, the automatic discharge transistor is active to discharge the output voltage through an 80Ω (TYP) resistor.

When the EN pin voltage is higher than 1V, the device is in active state, the input voltage is regulated to the output voltage and the automatic discharge transistor is turned off.

The EN pin is pulled down by internal 0.26μA (TYP) current source when the EN pin is floated. This current source will ensure the SGM2051 in shutdown state and reduce the power dissipation in system.

Adjustable Regulator

The output voltage of the SGM2051 can be adjusted from 0.5V to 3.3V. The ADJ pin will be connected with two external resistors as shown in Figure 4, the output voltage is determined by the following equation:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R_1}{R_2}\right) \quad (1)$$

where:

V_{OUT} is output voltage and V_{FB} is the internal voltage reference, V_{FB} = 0.5V.

One parallel capacitor (C_{FF}) with R_1 can be used to improve the feedback loop stability and PSRR, increase the transient response and reduce the output noise. Use $R_2 \leq 10k\Omega$ with C_{FF} in the range of 1nF to 100nF (effective capacitance), or choose $R_2 \leq 1.5k\Omega$ and the value of C_{FF} is unlimited.

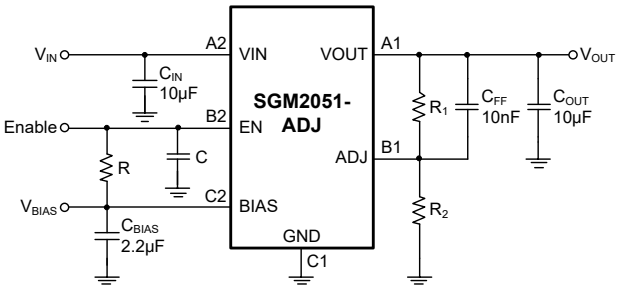


Figure 4. Adjustable Output Voltage Application

APPLICATION INFORMATION (continued)

Dropout Voltage

The SGM2051 specifies two dropout voltages because there are two power supplies V_{IN} and V_{BIAS} and one V_{OUT} regulator output. V_{IN} dropout voltage is defined as the difference between V_{IN} and V_{OUT} when V_{OUT} falls 5% below $V_{OUT(NOM)}$. When the output voltage is lower than 1.6V, V_{BIAS} dropout voltage is not applicable because the minimum bias supply voltage is 2.5V.

When V_{OUT} begins to decrease and V_{BIAS} is high enough, the V_{IN} dropout voltage equals to V_{IN} - V_{OUT}. V_{BIAS} dropout voltage refers to V_{BIAS} - V_{OUT} when the VIN and BIAS pins are connected together and V_{OUT} begins to decrease.

Output Current Limit and Short-Circuit Protection

When overload events happen, the output current is internally limited to 2.2A (TYP). When the VOUT pin is shorted to ground, the short-circuit protection will limit the output current to 1.1A (TYP).

Thermal Shutdown Protection

The SGM2051 can detect the temperature of die. When the die temperature exceeds the threshold value of thermal shutdown, the SGM2051 will be in shutdown state and it will remain in this state until the die temperature decreases to +140℃.

Power Dissipation (P_D)

Thermal protection limits power dissipation in the SGM2051. When power dissipation on pass element (P_D = (V_{IN} - V_{OUT}) × I_{OUT}) is too much that raise the operation junction temperature exceeds +160℃, the OTP circuit starts the thermal shutdown function and turns the pass element off. The power dissipation needs to be less than 6W when thermal protection occurs.

Therefore, thermal analysis for the chosen application is important to guarantee reliable performance over all conditions. To guarantee reliable operation, the junction temperature of the SGM2051 must not exceed 125℃.

In order to calculate the maximum power that the device can dissipate, the following formula is used:

$$P_{D(MAX)} = (125℃ - T_A) / \theta_{JA} \quad (2)$$

where T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance.

Negatively Biased Output

When the output is negative voltage, the chip may not start-up due to parasitic effects. Ensure that the output is greater than -0.3V under all conditions. The load is too high can make V_{OUT} < -0.3V, a Schottky diode can be added between the VOUT pin and GND pin.

Reverse Current Protection

The NMOS power transistor has an inherent body diode, this body diode will be forward biased when V_{OUT} > V_{IN}. When V_{OUT} > V_{IN}, the reverse current flowing from the VOUT pin to the VIN pin will damage the SGM2051. If V_{OUT} > (V_{IN} + 0.3V) is expected in the application, one external Schottky diode will be added between the VOUT pin and VIN pin to protect the SGM2051.

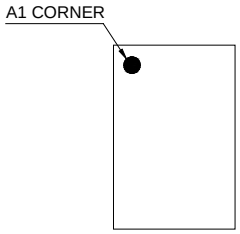
REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

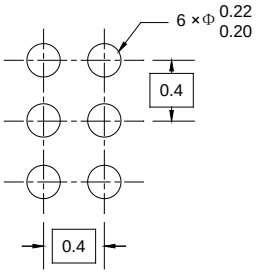
Changes from Original (JANUARY 2022) to REV.A	Page
Changed from product preview to production data	All

PACKAGE OUTLINE DIMENSIONS

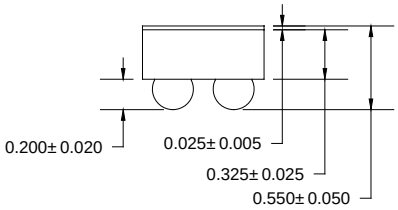
WLCSP-0.8×1.2-6B-A



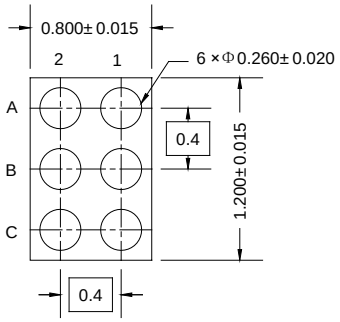
TOP VIEW



RECOMMENDED LAND PATTERN



SIDE VIEW

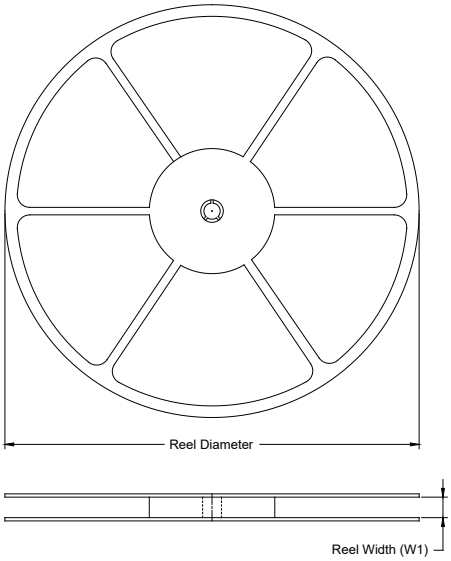


BOTTOM VIEW

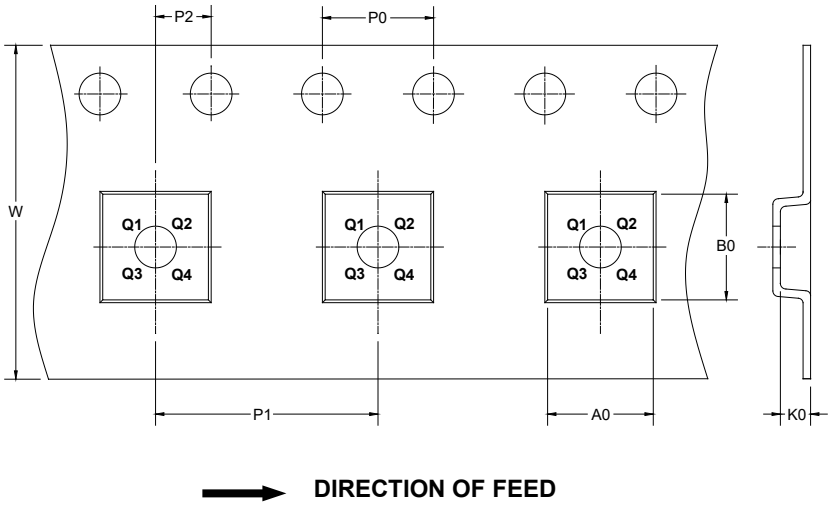
NOTE: All linear dimensions are in millimeters.

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



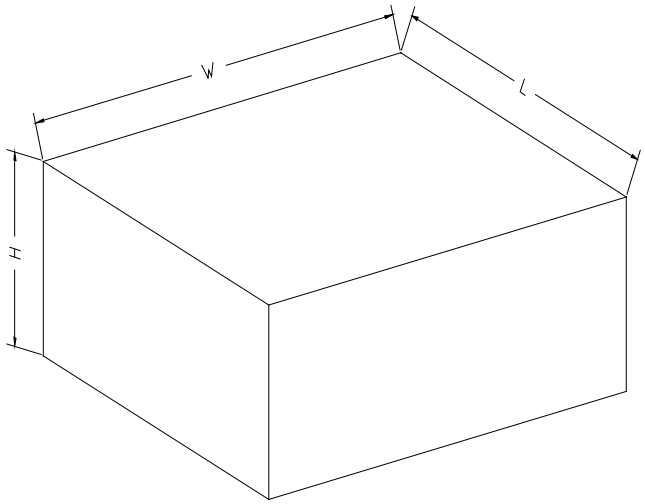
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
WLCSP-0.8×1.2-6B-A	7″	9.0	0.90	1.32	0.68	4.0	4.0	2.0	8.0	Q1

DD0001

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7″ (Option)	368	227	224	8
7″	442	410	224	18

DD0002